

54F/74F398 • 54F/74F399 Quad 2-Port Register

General Description

The 'F398 and 'F399 are the logical equivalents of a quad 2-input multiplexer feeding into four edge-triggered flip-flops. A common Select input determines which of the two 4-bit words is accepted. The selected data enters the flip-flops on the rising edge of the clock. The 'F399 is the 16-pin version of the 'F398, with only the Q outputs of the flip-flops available.

Features

- Select inputs from two data sources
- Fully positive edge-triggered operation
- Both true and complement outputs—'F398
- Guaranteed 4000V minimum ESD protection—'F399

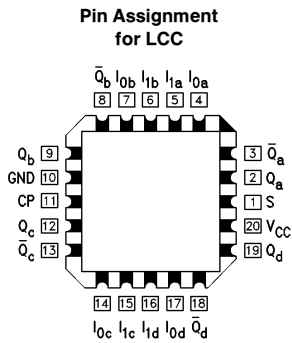
| Commercial | Military | Package Number | Package Description |
|-------------------|-------------------|----------------|---|
| 74F398PC | | N20A | 20-Lead (0.300" Wide) Molded Dual-In-Line |
| | 54F398DM (Note 2) | J20A | 20-Lead Ceramic Dual-In-Line |
| 74F398SC (Note 1) | | M20B | 20-Lead (0.300" Wide) Molded Small Outline, JEDEC |
| | 54F398FM (Note 2) | W20A | 20-Lead Cerpack |
| | 54F398LM (Note 2) | E20A | 20-Lead Ceramic Leadless Chip Carrier, Type C |
| 74F399PC | | N20A | 20-Lead (0.300" Wide) Molded Dual-In-Line |
| | 54F399DM (Note 2) | J20A | 20-Lead Ceramic Dual-In-Line |
| 74F399SC (Note 1) | | M20B | 20-Lead (0.300" Wide) Molded Small Outline, JEDEC |
| 74F399SJ (Note 1) | | M20D | 20-Lead (0.300" Wide) Molded Small Outline, EIAJ |
| | 54F399FM (Note 2) | W20A | 20-Lead Cerpack |
| | 54F399LM (Note 2) | E20A | 20-Lead Ceramic Leadless Chip Carrier, Type C |

Note 1: Devices also available in 13" reel. Use suffix = SCX and SJX.

Note 2: Military grade device with environmental and burn-in processing. Use suffix = DMQB, FMQB and LMQB.

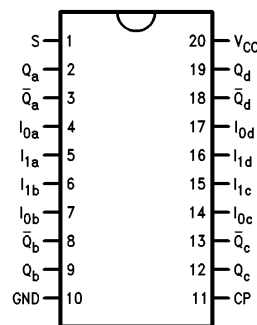
Connection Diagrams

'F398



TL/F/9533-5

Pin Assignment for DIP, SOIC and Flatpak

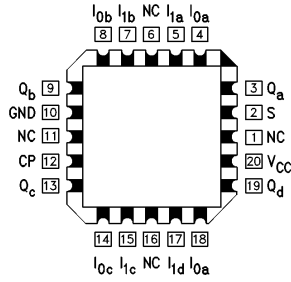


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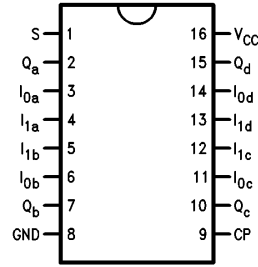
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Connection Diagrams (Continued)

'F399

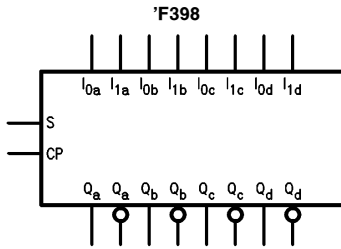


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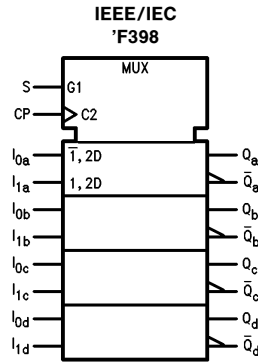


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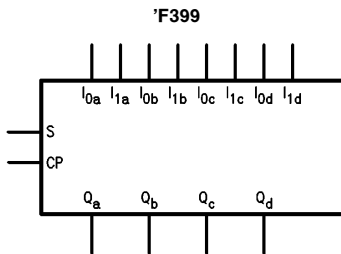
Logic Symbols



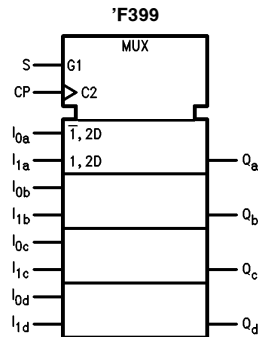
TL/F/9533-2



TL/F/9533-1



TL/F/9533-4



TL/F/9533-3

Unit Loading/Fan Out

| Pin Names | Description | 54F/74F | |
|-----------------------|--|------------------|---|
| | | U.L. HIGH/LOW | Input I_{IH}/I_{IL} Output I_{OH}/I_{OL} |
| S | Common Select Input | 1.0/1.0 | 20 μ A/ -0.6 mA |
| CP | Clock Pulse Input (Active Rising Edge) | 1.0/1.0 | 20 μ A/ -0.6 mA |
| $I_{0a}-I_{0d}$ | Data Inputs from Source 0 | 1.0/1.0 | 20 μ A/ -0.6 mA |
| $I_{1a}-I_{1d}$ | Data Inputs from Source 1 | 1.0/1.0 | 20 μ A/ -0.6 mA |
| Q_a-Q_d | Register True Outputs | 50/33.3 | -1 mA/20 mA |
| $\bar{Q}_a-\bar{Q}_d$ | Register Complementary Outputs ('F398) | 50/33.3 | -1 mA/20 mA |

Functional Description

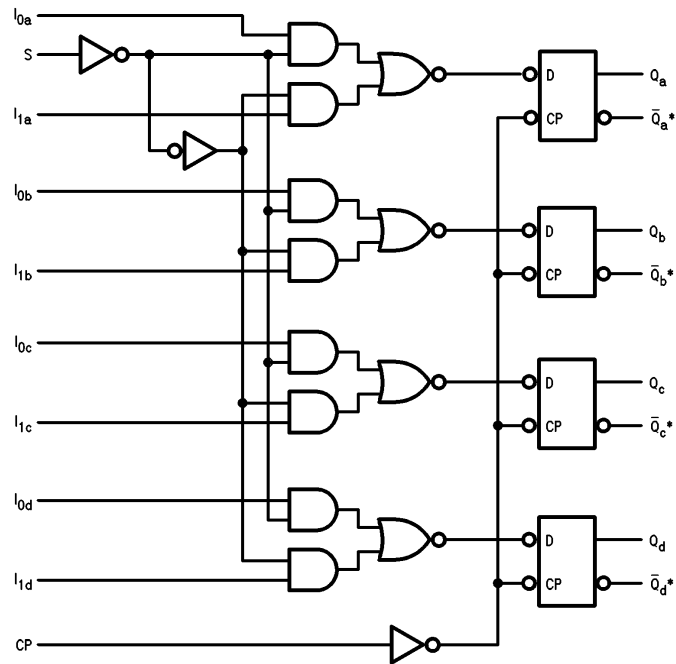
The 'F398 and 'F399 are high-speed quad 2-port registers. They select four bits of data from either of two sources (Ports) under control of a common Select input (S). The selected data is transferred to a 4-bit output register synchronous with the LOW-to-HIGH transition of the Clock input (CP). The 4-bit D-type output register is fully edge-triggered. The Data inputs (I_{0x} , I_{1x}) and Select input (S) must be stable only a setup time prior to and hold time after the LOW-to-HIGH transition of the Clock input for predictable operation. The 'F398 has both Q and \bar{Q} outputs.

Function Table

| Inputs | | | Outputs | |
|--------|-------|-------|---------|-------------|
| S | I_0 | I_1 | Q | \bar{Q}^* |
| l | l | X | L | H |
| l | h | X | H | L |
| h | X | l | L | H |
| h | X | h | H | L |

H = HIGH Voltage Level
 L = LOW Voltage Level
 h = HIGH Voltage Level one setup time prior to the LOW-to-HIGH clock transition
 l = LOW Voltage Level one setup time prior to the LOW-to-HIGH clock transition
 X = Immaterial
 *'F398 only

Logic Diagram



TL/F/9533-9

**F398 Only

Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

| | |
|---------------------------------|-----------------|
| Storage Temperature | –65°C to +150°C |
| Ambient Temperature under Bias | –55°C to +125°C |
| Junction Temperature under Bias | –55°C to +175°C |
| Plastic | –55°C to +150°C |

V_{CC} Pin Potential to Ground Pin –0.5V to +7.0V

Input Voltage (Note 2) –0.5V to +7.0V

Input Current (Note 2) –30 mA to +5.0 mA

Voltage Applied to Output in HIGH State (with V_{CC} = 0V)
 Standard Output –0.5V to V_{CC}
 TRI-STATE® Output –0.5V to +5.5V

Current Applied to Output in LOW State (Max) twice the rated I_{OL} (mA)

ESD Last Passing Voltage (Min)—F399 4000V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Recommended Operating Conditions

| | |
|------------------------------|-----------------|
| Free Air Ambient Temperature | |
| Military | –55°C to +125°C |
| Commercial | 0°C to +70°C |
| Supply Voltage | |
| Military | +4.5V to +5.5V |
| Commercial | +4.5V to +5.5V |

DC Electrical Characteristics

| Symbol | Parameter | 54F/74F | | | Units | V _{CC} | Conditions |
|------------------|-----------------------------------|--|-------------------|-------------|-------|-----------------|---|
| | | Min | Typ | Max | | | |
| V _{IH} | Input HIGH Voltage | 2.0 | | | V | | Recognized as a HIGH Signal |
| V _{IL} | Input LOW Voltage | | | 0.8 | V | | Recognized as a LOW Signal |
| V _{CD} | Input Clamp Diode Voltage | | | –1.2 | V | Min | I _{IN} = –18 mA |
| V _{OH} | Output HIGH Voltage | 54F 10% V _{CC} 74F 10% V _{CC} 74F 5% V _{CC} | 2.5 2.5 2.7 | | V | Min | I _{OH} = –1 mA I _{OH} = –1 mA I _{OH} = –1 mA |
| V _{OL} | Output LOW Voltage | 54F 10% V _{CC} 74F 10% V _{CC} | | 0.5 0.5 | V | Min | I _{OL} = 20 mA I _{OL} = 20 mA |
| I _{IH} | Input HIGH Current | 54F 74F | | 20.0 5.0 | μA | Max | V _{IN} = 2.7V |
| I _{BVI} | Input HIGH Current Breakdown Test | 54F 74F | | 100 7.0 | μA | Max | V _{IN} = 7.0V |
| I _{CEX} | Output HIGH Leakage Current | 54F 74F | | 250 50 | μA | Max | V _{OUT} = V _{CC} |
| V _{ID} | Input Leakage Test | 74F | 4.75 | | V | 0.0 | I _{ID} = 1.9 μA All Other Pins Grounded |
| I _{OD} | Output Leakage Circuit Current | 74F | | 3.75 | μA | 0.0 | V _{IOD} = 150 mV All Other Pins Grounded |
| I _{IL} | Input LOW Current | | | –0.6 | mA | Max | V _{IN} = 0.5V |
| I _{OS} | Output Short-Circuit Current | | –60 | –150 | mA | Max | V _{OUT} = 0V |
| I _{CCH} | Power Supply Current (F398) | | 25 | 38 | mA | Max | V _O = HIGH |
| I _{CCL} | Power Supply Current (F398) | | 25 | 38 | mA | Max | V _O = LOW |
| I _{CCH} | Power Supply Current (F399) | | 22 | 34 | mA | Max | V _O = HIGH |
| I _{CCL} | Power Supply Current (F399) | | 22 | 34 | mA | Max | V _O = LOW |

AC Electrical Characteristics

| Symbol | Parameter | 74F | | | 54F | | 74F | | Units | |
|--------------------------------------|---|---|-----|-----|--|-----|--|-----|-------|----|
| | | T _A = +25°C V _{CC} = +5.0V C _L = 50 pF | | | T _A , V _{CC} = Mil C _L = 50 pF | | T _A , V _{CC} = Com C _L = 50 pF | | | |
| | | Min | Typ | Max | Min | Max | Min | Max | | |
| f _{max} | Input Clock Frequency | 100 | 140 | | 80 | | 100 | | MHz | |
| t _{PLH} t _{pHL} | Propagation Delay CP to Q or \bar{Q} | 3.0* | 5.7 | 7.5 | 3.0 | 9.5 | 3.0 | 8.5 | 10.0 | ns |

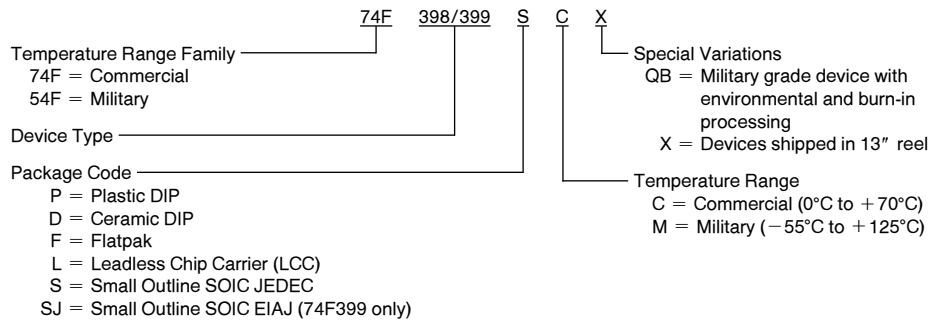
*F398 3.3 ns

AC Operating Requirements

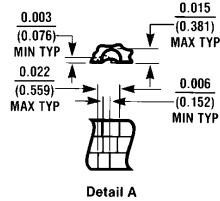
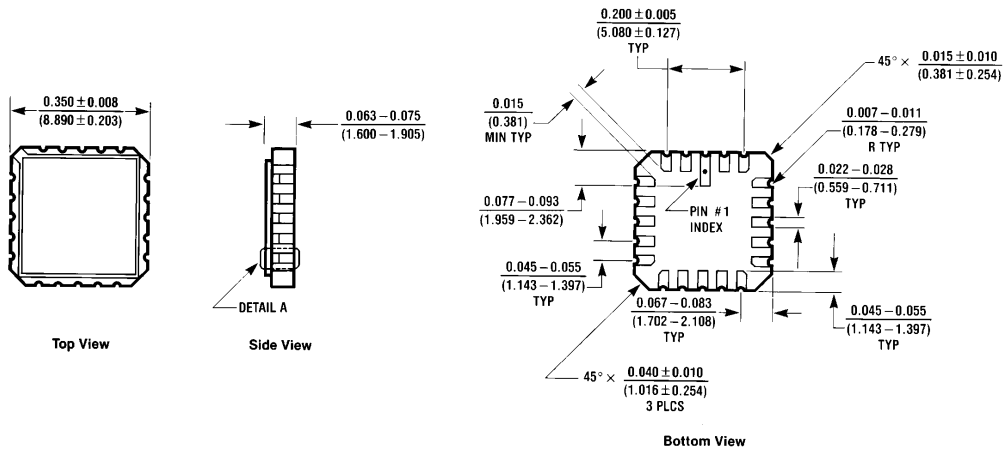
| Symbol | Parameter | 74F | | 54F | | 74F | | Units |
|--|---|---|-----|--|-----|--|-----|-------|
| | | T _A = +25°C V _{CC} = +5.0V | | T _A , V _{CC} = Mil | | T _A , V _{CC} = Com | | |
| | | Min | Max | Min | Max | Min | Max | |
| t _s (H) t _s (L) | Setup Time, HIGH or LOW I _n to CP | 3.0 | | 4.5 | | 3.0 | | ns |
| t _h (H) t _h (L) | Hold Time, HIGH or LOW I _n to CP | 1.0 | | 1.5 | | 1.0 | | |
| t _s (H) t _s (L) | Setup Time, HIGH or LOW S to CP (*F398) | 7.5 | | 10.5 | | 8.5 | | ns |
| t _s (H) t _s (L) | Setup Time, HIGH or LOW S to CP (*F399) | 7.5 | | 9.5 | | 8.5 | | |
| t _h (H) t _h (L) | Hold Time, HIGH or LOW S to CP | 0 | | 0 | | 0 | | ns |
| t _w (H) t _w (L) | CP Pulse Width HIGH or LOW | 4.0 | | 4.0 | | 4.0 | | |
| | | 5.0 | | 7.0 | | 5.0 | | |

Ordering Information

The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:

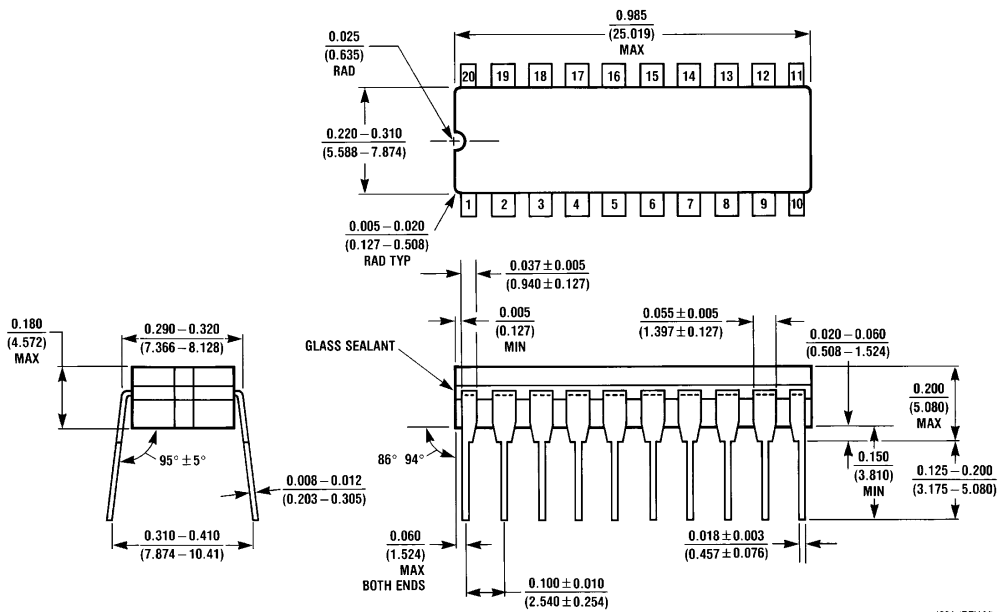


Physical Dimensions inches (millimeters)



20-Lead Ceramic Leadless Chip Carrier (L)
 NS Package Number E20A

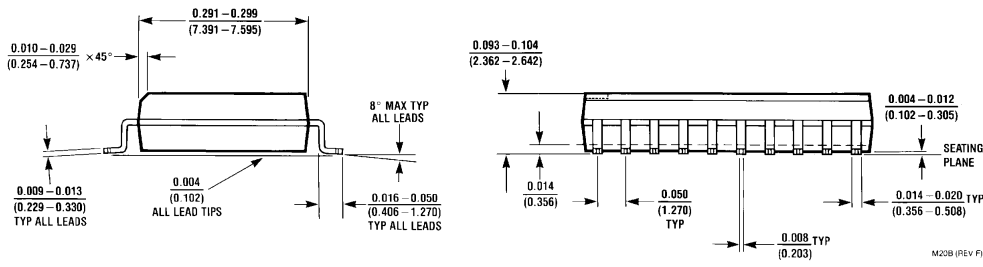
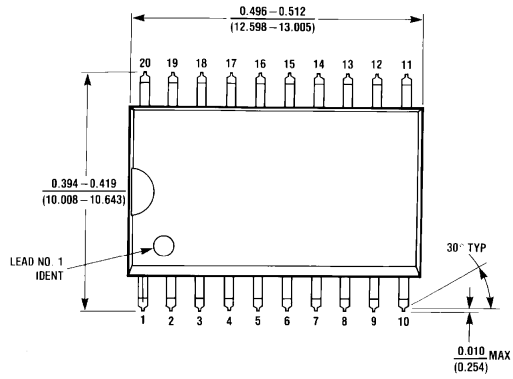
E20A (REV D)



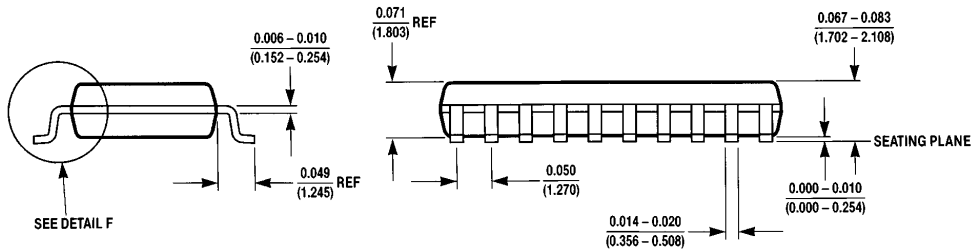
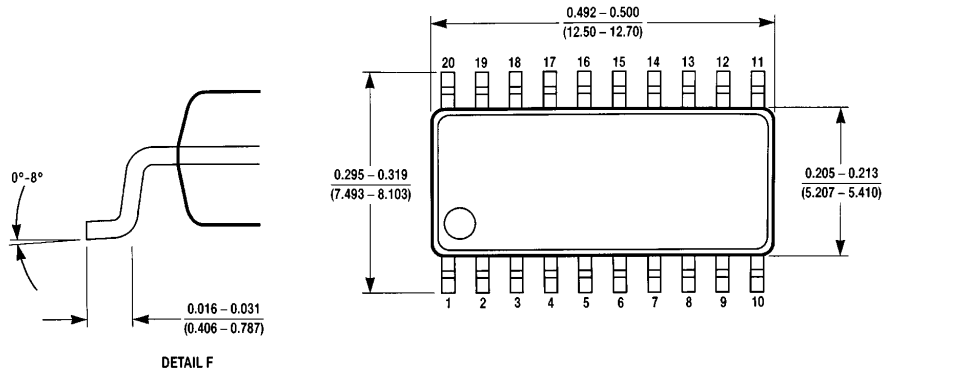
20-Lead Ceramic Dual-In-Line Package (D)
 NS Package Number J20A

J20A (REV M)

Physical Dimensions inches (millimeters) (Continued)

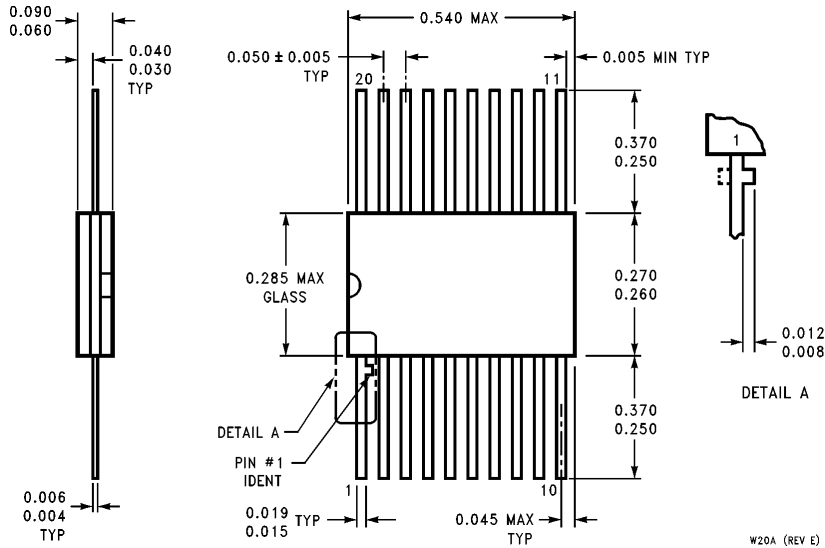


20-Lead (0.300" Wide) Molded Small Outline Package, JEDEC (S)
NS Package Number M20B



20-Lead (0.300" Wide) Molded Small Outline Package, EIAJ (SJ)
NS Package Number M20D

Physical Dimensions inches (millimeters) (Continued)



**20-Lead Ceramic Flatpak (F)
NS Package Number W20A**

W20A (REV E)

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